2SD1835

Bipolar Transistor 50V, 2A, Low VCE(sat), NPN Single NP



Applications

· Voltage regulators, relay drivers, lamp drivers, electrical equipment

Features

- Adoption of FBET, MBIT processes
- Large current capacity
- Low collector-to-emitter saturation voltage
- Fast switching time

Specifications

Absolute Maximum Ratings at Ta=25°C

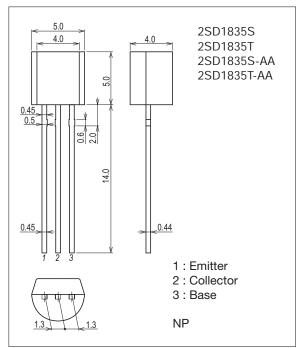
Symbol	Conditions	Ratings	Unit
VCBO		60	V
VCEO		50	V
VEBO		6	V
IC		2	А
ICP		3	Α
PC		0.75	W
Tj		150	°C
Tstg		-55 to +150	°C
	VCBO VCEO VEBO IC ICP PC Tj	VCBO VCEO VEBO IC ICP PC Tj	VCBO 60 VCEO 50 VEBO 6 IC 2 ICP 33 PC 0.75 Tj 150

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

7522-002



Product & Package Information

• Package : NP

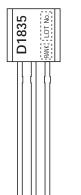
: SC-34A, TO-92, TO-226AA, SOT-54

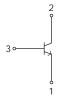
• Minimum Packing Quantity : 1,500 pcs./box, 500pcs./bag

Marking

• JEITA, JEDEC

Electrical Connection





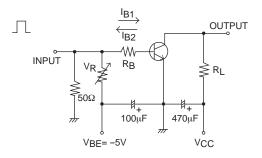
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions			Unit	
Parameter	Symbol	Conditions	min	typ	max	UTIIL
Collector Cutoff Current	ICBO	VCB=50V, IE=0A			100	nA
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0A			100	nA
DC Current Gain	h _{FE} 1	V _{CE} =2V, I _C =100mA	100*		560*	
	h _{FE} 2	V _{CE} =2V, I _C =1.5A	40			
Gain-Bandwidth Product	fT	VCE=10V, IC=50mA		150		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		12		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	IC=1A, IB=50mA		0.15	0.4	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=1A, IB=50mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μΑ, IE=0A	60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0A	6			V
Turn-ON Time	ton			60		ns
Storage Time	tstg	See specified Test Circuit.		550		ns
Fall Time	tf			30		ns

 * : The 2SD1835 is classified by 100mA hFE as follows :

Rank	R	S	Т	U
hFE	100 to 200	140 to 280	200 to 400	280 to 560

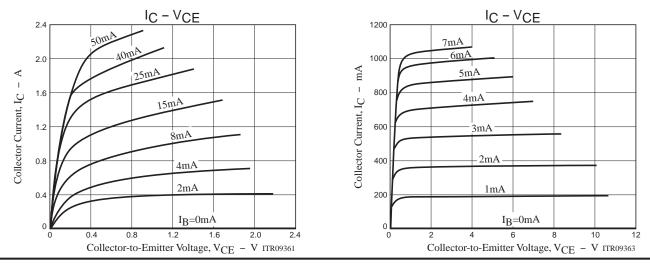
Switching Time Test Circuit

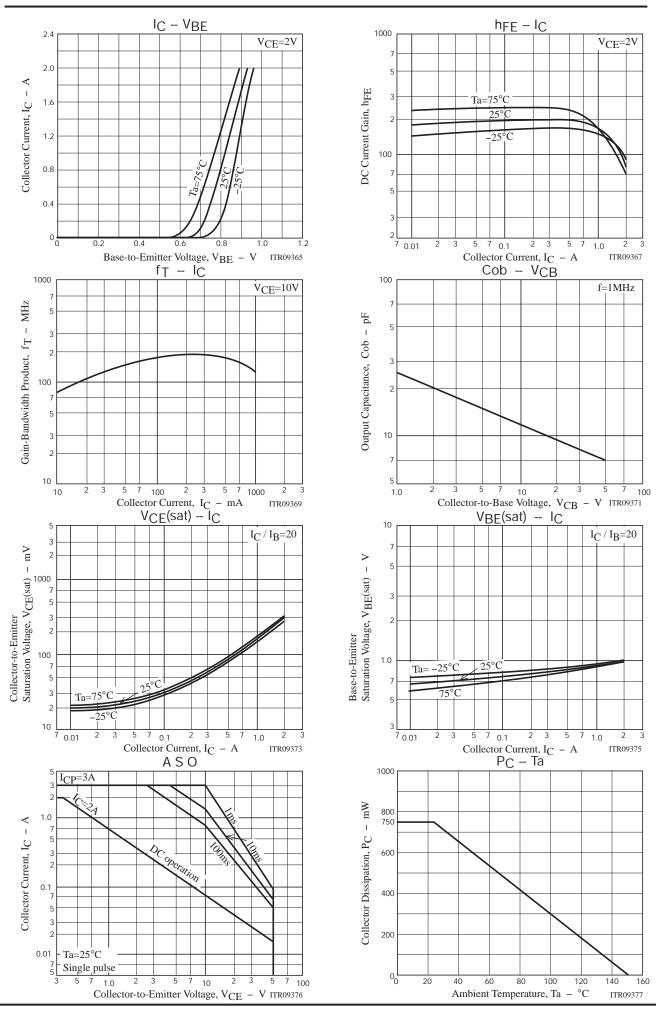


 $I_{C}=10I_{B1}=-10I_{B2}=500mA, V_{CC}=25V$

Ordering Information

Device	Package	Shipping	memo
2SD1835S	NP	500pcs./bag	
2SD1835T	NP	500pcs./bag	Pb Free
2SD1835S-AA	NP	1,500pcs./box	PDFlee
2SD1835T-AA	NP	1,500pcs./box	

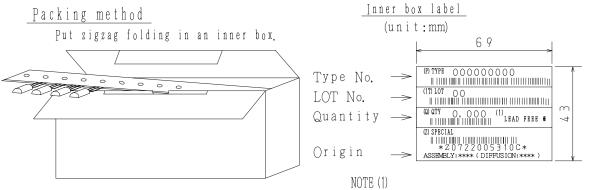




Taping Specification 2SD1835S-AA, 2SD1835T-AA

1. Packing Format

Package Name	Packing Type	Maximum Number of devices contained (pcs) Inner BOX (C-2) number of contained	Packing format Outer BOX (C-6)
N P	ΑA	Dimensions:nm (external) $1, 500$ $330 \times 45 \times 145$	16 inner boxes contained (24,000pcs) Dimensions:mm (external) 5 8 5 × 3 4 5 × 2 0 0

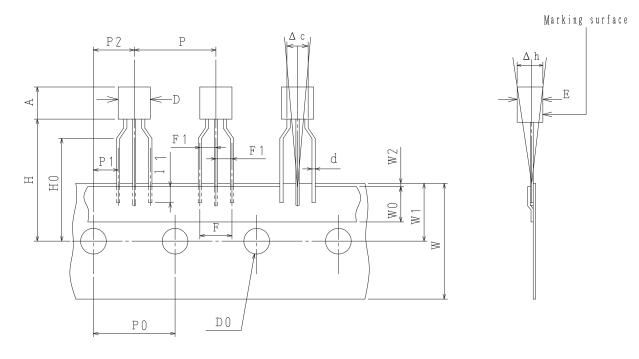


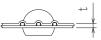
NOTE (1) The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping specifications

2-1. Carrier tape size





2-2. Taping size standard

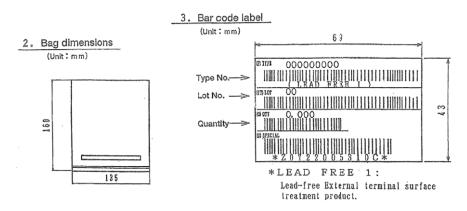
unit:mm

[t e m	Symbol	Standard	Tolerance		Item	Symbol	Standard	Tolerance
Work piece outside diameter	D	50	±0.2		Tape width	W	18.0	+1.0 -0.5
WOLV DIECE ONTRINE ALUMETEL	E	4.0	±0.2		Adhesive tape	WO	60	±1.5
Work piece height	А	5.0	±0.2		Displacement of perforations		9.0	±0.5
Lead wire diameter	d	0.45×0.44t	±0. 1		Work piece bottom surface position	Η	19, 0	±1.0
Bonded lead wire	1 1	2. OMIN			Insert stopper position	ΗΟ	16.0	±0.5
Pitch between products	Р	12.7	±0.5		Work piece upper limit position	Η1	24, 5	±1.5
Pitch between perforations	Ρ0	12.7	±0.2		Perforations diameter	D ()	φ4. ()	±0.2
Distance between lead wire	F	5.0	+0.8 -0.2		Tape thickness	t	06	±0.2
Lead wire pitch distance	F 1	2.5	+0.2		Product inclination	\triangle C	0	±1.0
Product inclination	riangle h	0	±2.0					
Displacement of perforations	P 1	3, 85	±0.3	Me th	asurement position is e bottom of the clinch			
	P 2	6 35	±0.3					
Displacement of tape	W 2	0. 5MAX			t to be displaced to e outside of the board			

Bag Packing Specification 2SD1835S, 2SD1835T

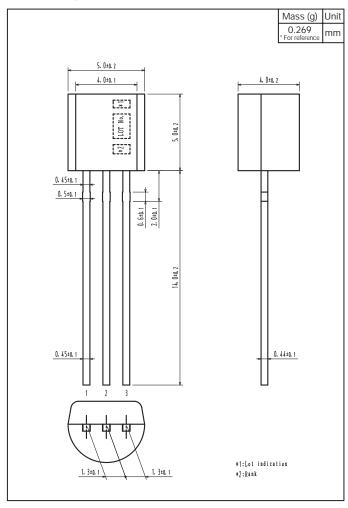
1 . Packing condition

Storange package		Maximum number of devices contained (pcs.)			Packing condition			
	outline name	Bags	Inner box	Devices contained	Outer box (A-1)	Outer box ($A-2$)
	NP	500	$\begin{array}{c} B-1 \text{ Inner box dimensions :} \\ mm \text{ (external)} \\ 4 4 5 \times 2 2 5 \times 5 5 \end{array}$		5 inner boxes Outer box din 470 × 250 ×	nensions : i	mm (external)	3 inner boxes contained 30, 00 Outer box dimensions : mm (external) 470 × 250 × 190



Outline Drawing

2SD1835S, 2SD1835T



2SD1835

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